### **Technical Information** Thyristor / Diode Modules

**MS TD430** 





#### **Key Parameters**

Vdrm / Vrrm	= 2400V
IT(AV)	= 430A
Тѕм	= 17000A
V <sub>T(TO)</sub>	= 0.95V
rт	= 0.45mΩ

#### Features

- Full blocking capability over wide temperature range
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Pressure contacts technology for high reliability
- UL Recognized, file no. E505556

- ApplicationsPower Supplies
- DC motor control .
- **Controlled Rectifiers**
- AC switch

### **Ordering Information**

MS	TD	430	К	24	
Fixed code	TD- Thyristor- Diode Module	Current Code	Technology K = Pressure Contact Technology	Voltage Code Code X 100 = V <sub>DRM</sub> /V <sub>RRM</sub>	
Order Code MS TD430K24 : 2400V VDRM, VRRM, Thyristor-Diode Module					
			Prepared by : ABA Dat	e of Publication : 25.03.2015	
			Approved by : RBS Rev	ision : 1	

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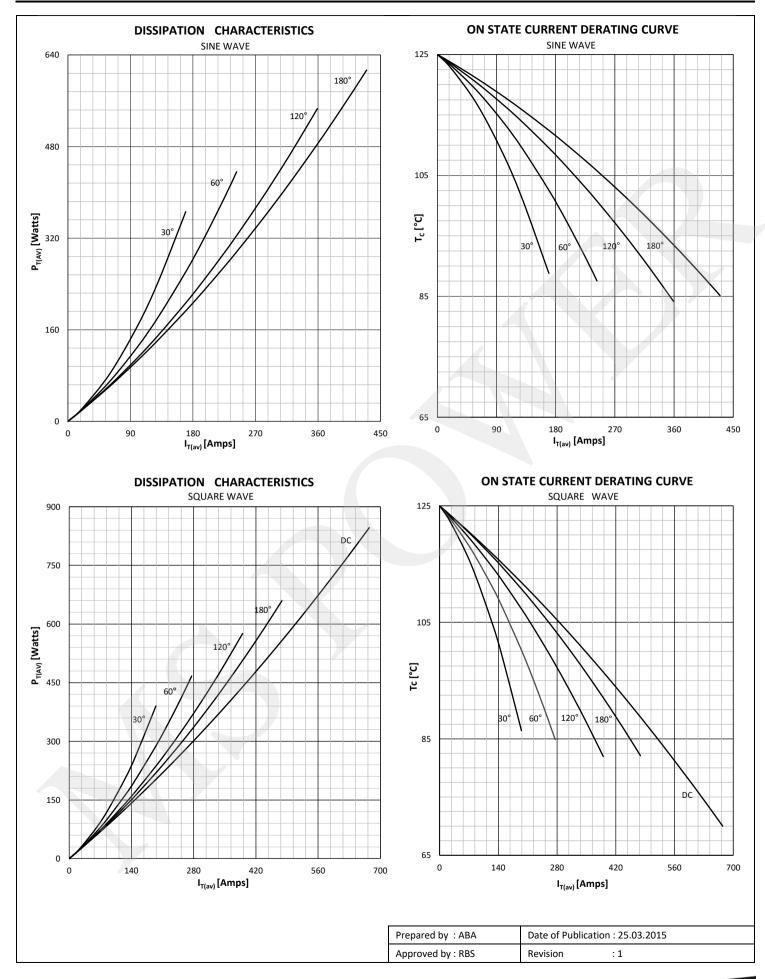


Symbol	Characteristic	Conditions	Тј [°С]	Value	Unit
BLOCKI	NG				
V RRM	Repetitive peak reverse voltage		125	2000 - 2400	V
V RSM	Non-repetitive peak reverse voltage		125	2100 - 2500	V
V drm	Repetitive peak off-state voltage		125	2000 - 2400	V
I RRM	Repetitive peak reverse current	V= V rrm	125	100	mA
I DRM	Repetitive peak off-state current	V= V drm	125	100	mA
CONDU	CTING				
I T (AV)	Mean on state current	180° sin ,50 Hz, T <sub>c</sub> =85°C		430	Α
I RMS	RMS on-state current			675	А
		Sine wave, 10 ms	25	17000	А
I TSM	Surge on-state current	Without reverse voltage	125	15000	A
			25	1445 x 10 <sup>3</sup>	A <sup>2</sup> s
l² t	l² t	Sine wave, 10 ms Without reverse voltage	125	1125 x 10 <sup>3</sup>	A <sup>2</sup> s
\ <i>I</i> -					
Vт	On-state voltage	On-state current = 1500A	125	1.78	V
V T(TO)	Threshold voltage		125	0.95	V
rт	On-state slope resistance		125	0.45	mΩ
SWITCH	ING			1	
di/dt	Critical rate of rise of on-state current	$V_D = 67\%V_{DRM}$ , $I_{GM}=1A$ , $di_G/dt = 1A/\mu s$ , f=50Hz	125	150	A/µs
dv/dt	Critical rate of rise of off-state voltage	$V_{DR} = 67\% V_{DRM}$	125	1000	V/µs
GATE					
l <sub>gt</sub>	Gate trigger current	V <sub>D</sub> =6V	25	200	mA
V <sub>gt</sub>	Gate trigger voltage	V <sub>D</sub> =6V	25	3.0	V
Iн	Holding current	$V_D=6V$ , gate open circuit	25	300	mA
ΙL	Latching current	V <sub>D</sub> =6V	25	1500	mA
MOUNT	ING				
R th(j-c)	Thermal impedance, sin 180°	Junction to case, per arm per module		0.0650 0.0325	°C/W
R th(j-c)	Thermal impedance, rec120°	Junction to case, per arm per module		0.0323	°C/W
R th(c-h)	Thermal impedance	Case to heatsink, per arm per module		0.02 0.01	°C/W
Тj	Max. junction temperature			125	°C
T stg	Storage temperature			-40 150	°C
VISOL	Insulation test voltage,RMS	F=50Hz, 1min		3.0	KV
M1	Mounting torque			6 ± 15%	Nm
M2	Terminal connection torque			12 ± 15%	Nm
W	Weight (Approx.)			1450	gm
<b>91</b> *	File No.			E505556	

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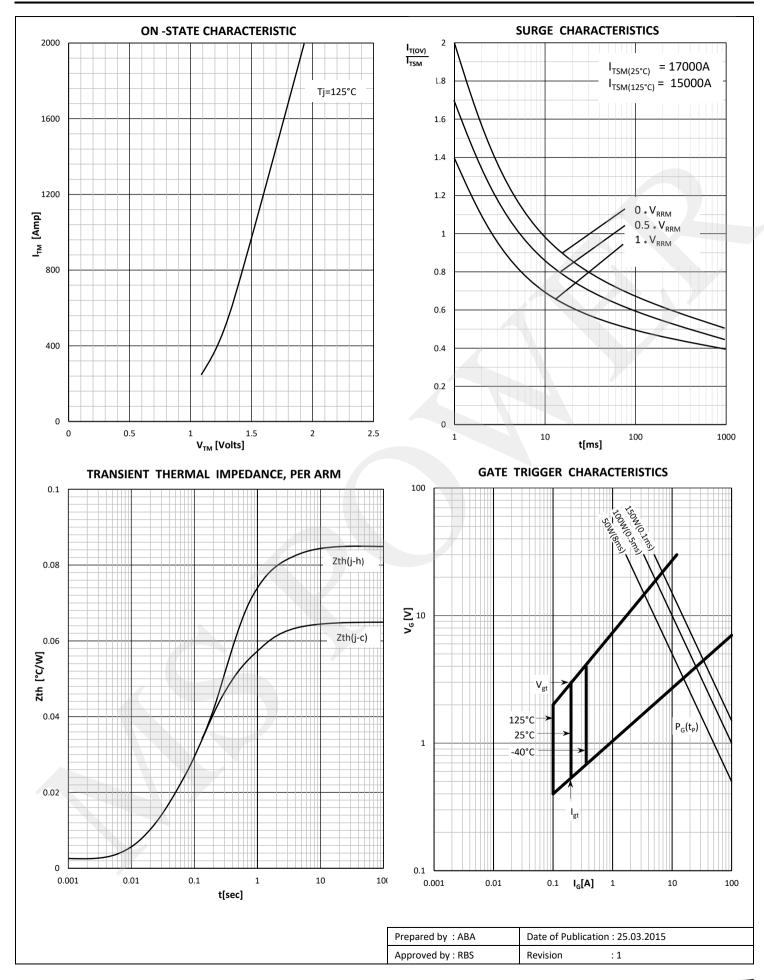
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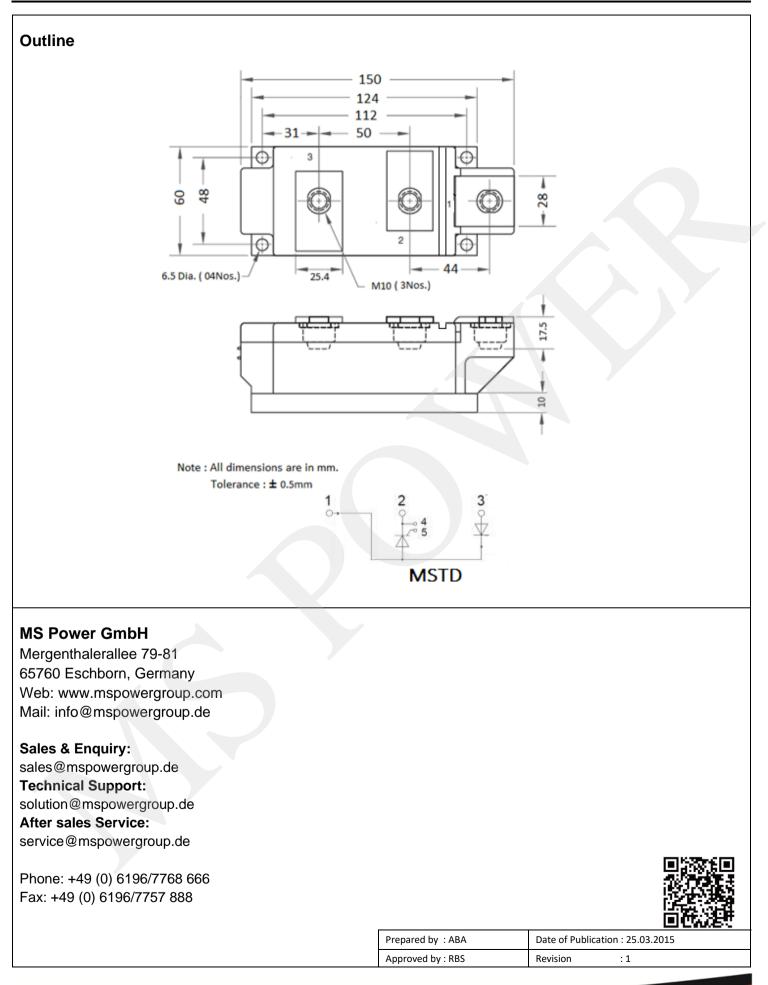




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